

30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

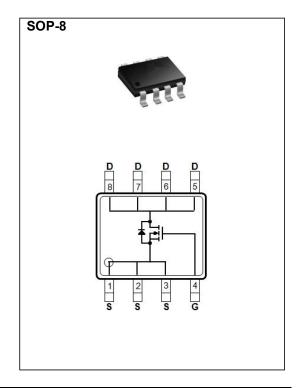
18 A

Features

- R_{DS(ON)}, V_{GS}@10V, I_D@10A<4.2mΩ
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@5A<6m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance

Mechanical Data

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20		
Continuous Drain Current	T _A =25°C		16		
	T _A =70°C	l _D	13	A	
Pulsed Drain Current (Note 1)		I _{DM}	64		
Power Dissipation	T _A =25°C	<u> </u>	2.1	W	
	T _A =70°C	P _D	1.3		
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 5)		$R_{ heta JA}$	59.5	°C/W	



Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA V _{DS} =V _{GS} , I _D =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$		1	1.6	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =10A	-	3.5	4.2	mΩ
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =5A	-	5.2	6	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	V _{DS} =15V, I _D =24A, V _{GS} =4.5V ^(Note 2,3)	-	23	-	nC
Gate-Source Charge	Q_gs		-	8	-	
Gate-Drain Charge	Q_gd		-	9	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	2436	-	pF
Output Capacitance	Coss		-	306	-	
Reverse Transfer Capacitance	Crss		-	196	-	
Turn-On Delay Time	td _(on)	\/ _45\/ _45\	-	32	-	
Turn-On Rise Time	tr	V_{DS} =15V, I_{D} =15A, V_{GS} =10V, R_{G} =1 Ω (Note 2,3)	-	169	-	ns
Turn-Off Delay Time	td _(off)		-	232	-	
Turn-Off Fall Time	tf		-	170	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	l _o				16	Α
Diode Forward Current	IS	ls		-	10	^
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.66	1	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 5. R_{ΘJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

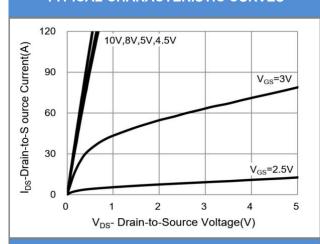


Fig.1 On-Region Characteristics

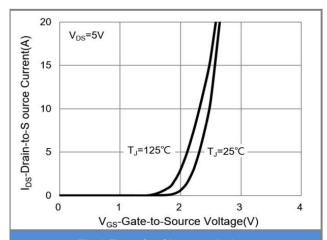


Fig.2 Transfer Characteristics

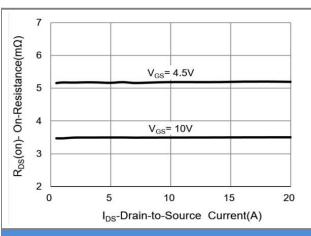


Fig.3 On-Resistance vs. Drain Current

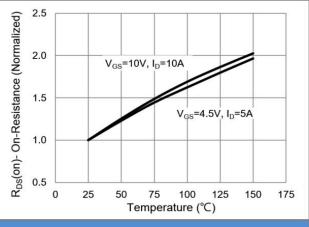


Fig.4 On-Resistance vs. Junction temperature

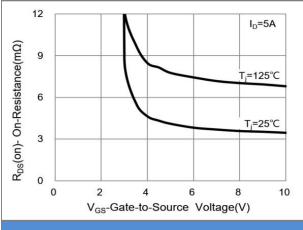


Fig.5 On-Resistance Variation with V_{GS}

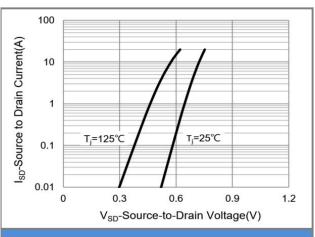


Fig.6 Body Diode Characteristics



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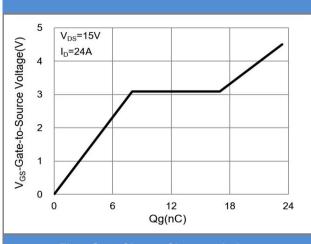


Fig.7 Gate-Charge Characteristics

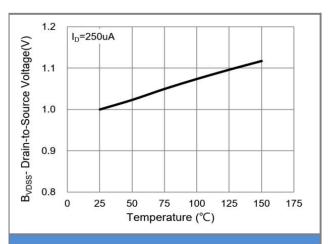


Fig.8 Breakdown Voltage Variation vs. Temperature

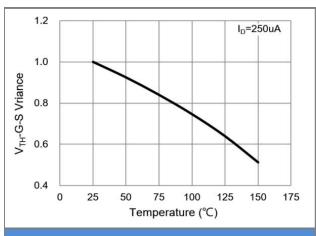


Fig.9 Threshold Voltage Variation with Temperature

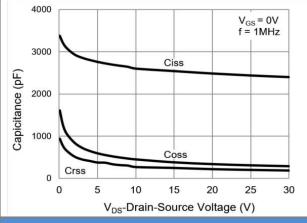


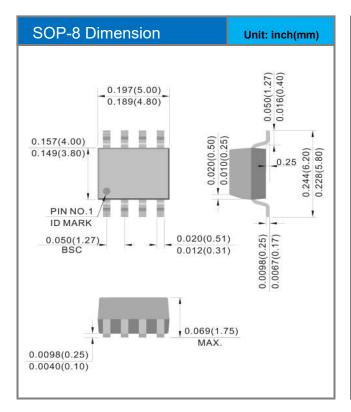
Fig.10 Capacitance vs. Drain-Source Voltage

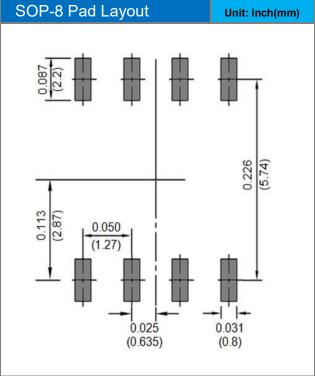


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type		
CSM320N18SOP8	SOP-8	2.5K pcs / 13" reel		

Packaging Information & Mounting Pad Layout







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